

74LCX374

Low-Voltage Octal D Flip-Flop with 5V Tolerant Inputs and Outputs

General Description

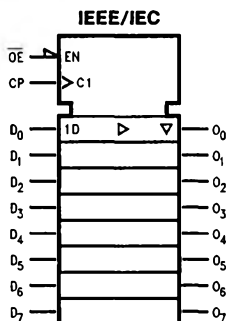
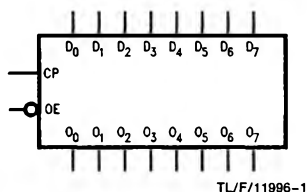
The LCX374 consists of eight D-type flip-flops featuring separate D-type inputs for each flip-flop and TRI-STATE® outputs for bus-oriented applications. A buffered clock (CP) and Output Enable ($\overline{OE}$) are common to all flip-flops. The LCX374 is designed for low-voltage (3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX374 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

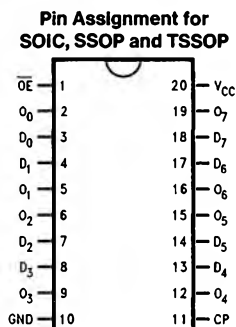
Features

- 5V tolerant inputs and outputs
- 8.5 ns t_{PD} max, 10 μA I_{CCQ} max
- Power-down high impedance inputs and outputs
- 2.0V–3.6V V_{CC} supply operation
- ± 24 mA output drive
- Implements patented Quiet Series™ noise/EMI reduction circuitry
- Functionally compatible with the 74 series 374
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human Body Model > 2000V
 - Machine Model > 200V

Logic Symbols



Connection Diagram



Pin Names	Description
D_0 – D_7	Data Inputs
CP	Clock Pulse Input
$\overline{OE}$	Output Enable Input
Q_0 – Q_7	TRI-STATE Outputs

	SOIC JEDEC	SOIC EIAJ	SSOP Type II	TSSOP JEDEC
Order Number	74LCX374WM 74LCX374WMX	74LCX374SJ 74LCX374SJX	74LCX374MSA 74LCX374MSAX	74LCX374MTC 74LCX374MTCX
See NS Package Number	M20B	M20D	MSA20	MTC20

Functional Description

The LCX374 consists of eight edge-triggered flip-flops with individual D-type inputs and TRI-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ($\overline{OE}$) LOW, the contents of the eight flip-flops are available at the outputs. When the $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

Truth Table

Inputs			Outputs
D_n	CP	$\overline{OE}$	O_n
H		L	H
L		L	L
X	L	L	O_0
X	X	H	Z

H = HIGH Voltage Level

L = LOW Voltage Level

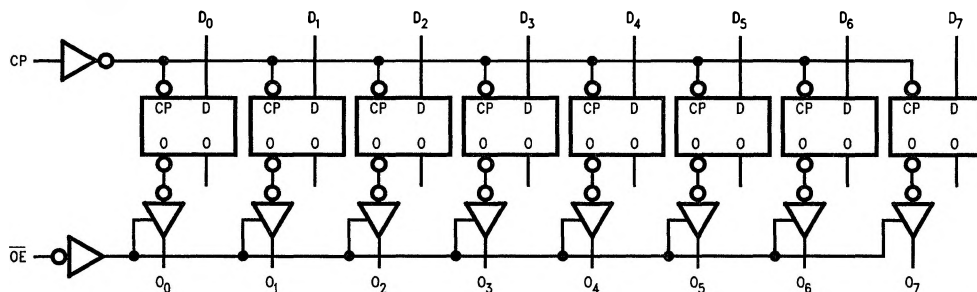
X = Immaterial

Z = High Impedance

 = LOW-to-HIGH Transition

O_0 = Previous O_0 before HIGH to LOW of CP

Logic Diagram



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Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	-0.5 to +7.0		V
V_I	DC Input Voltage	-0.5 to +7.0		V
V_O	DC Output Voltage	-0.5 to +7.0	Output in TRI-STATE	V
		-0.5 to $V_{CC} + 0.5$	Output in High or Low State (Note 2)	V
I_{IK}	DC Input Diode Current	-50	$V_I < GND$	mA
I_{OK}	DC Output Diode Current	-50	$V_O < GND$	mA
		+50	$V_O > V_{CC}$	
I_O	DC Output Source/Sink Current	± 50		mA
I_{CC}	DC Supply Current per Supply Pin	± 100		mA
I_{GND}	DC Ground Current per Ground Pin	± 100		mA
T_{STG}	Storage Temperature	-65 to +150		°C

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6
		Data Retention	1.5	3.6
V_I	Input Voltage	0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}
		TRI-STATE	0	5.5
I_{OH}/I_{OL}	Output Current	$V_{CC} = 3.0V-3.6V$ $V_{CC} = 2.7V$	± 24	mA
			± 12	
T_A	Free-Air Operating Temperature	-40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, $V_{IN} = 0.8V-2.0V$, $V_{CC} = 3.0V$	0	10	ns/V

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		Units
				Min	Max	
V_{IH}	HIGH Level Input Voltage		2.7-3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7-3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.7-3.6	$V_{CC} - 0.2$		V
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		V
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.7-3.6		0.2	V
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	V
		$I_{OL} = 16 \text{ mA}$	3.0		0.4	V
		$I_{OL} = 24 \text{ mA}$	3.0		0.55	V
I_I	Input Leakage Current	$0 \leq V_I \leq 5.5V$	2.7-3.6		± 5.0	μA
I_{OZ}	TRI-STATE Output Leakage	$0 \leq V_O \leq 5.5V$ $V_I = V_{IH}$ or V_{IL}	2.7-3.6		± 5.0	μA
I_{OFF}	Power-Off Leakage Current	V_I or $V_O = 5.5V$	0		100	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7-3.6		10	μA
		$3.6V \leq V_I, V_O \leq 5.5V$	2.7-3.6		± 10	μA
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7-3.6		500	μA

AC Electrical Characteristics

Symbol	Parameter	T _A = −40°C to +85°C				Units
		V _{CC} = 3.3V ±0.3V		V _{CC} = 2.7V		
		Min	Max	Min	Max	
t _{MAX}	Maximum Clock Frequency	150				MHz
t _{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	ns
t _{PLH}	CP to O _n	1.5	8.5	1.5	9.5	
t _{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	ns
t _{PZH}		1.5	8.5	1.5	9.5	
t _{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	ns
t _{PHZ}		1.5	7.5	1.5	8.5	
t _s	Setup Time	2.5		2.5		ns
t _H	Hold Time	1.5		1.5		ns
t _W	Pulse Width	3.3		3.3		ns
t _{OSHL}	Output to Output Skew (Note 1)		1.0			ns
t _{OSLH}			1.0			

Note 1: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Dynamic Switching Characteristics

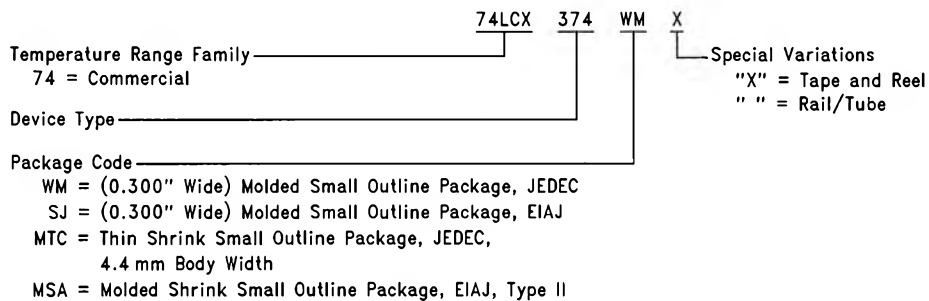
Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25^{\circ}\text{C}$	Units
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50\text{ pF}$, $V_{\text{IH}} = 3.3\text{V}$, $V_{\text{IL}} = 0\text{V}$	3.3	0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50\text{ pF}$, $V_{\text{IH}} = 3.3\text{V}$, $V_{\text{IL}} = 0\text{V}$	3.3	0.8	V

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = \text{Open}$, $V_I = 0\text{V}$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3\text{V}$, $V_I = 0\text{V}$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3\text{V}$, $V_I = 0\text{V}$ or V_{CC} , $F = 10\text{ MHz}$	25	pF

74LCX374 Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



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